**Product data sheet** 

# 1. General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO247 plastic package





### 2. Features and benefits

- High junction temperature up to 175°C
- · Low forward voltage drop, negligible switching losses
- High efficiency

# 3. Applications

- DC to DC converters
- · Freewheeling diode
- · OR-ing diode
- · Switched mode power supply rectifier

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit		
Absolute	Absolute maximum rating								
$V_{RRM}$	repetitive peak reverse voltage				200		V		
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3			20		А		
$I_{O(AV)}$	average output current	$\delta$ = 0.5 ; square-wave pulse; both diodes conducting		40		А			
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit		
Static ch	aracteristics								
$V_{F}$	forward voltage	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; per diode; <u>Fig. 6</u>		-	0.85	0.92	V		
I <sub>R</sub>	reverse current	$V_R = 200 \text{ V}$ ; $T_j = 25 \text{ °C}$ ; per diode; Fig. 7		-	0.1	5	μΑ		

# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	K	cathode		A1
3	A2	anode 2		K 8ym125
mb	К	mounting base; connected to cathode	TO247	· ·

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package	Orderable part number	Packing	Small packing	Package	Package
	name		method	quantity	version	issue date
WN3S40200CWT	TO247	WN3S40200CWTQ	Tube	30	TO247P	09-Mar-2023

# 7. Marking

### **Table 4. Marking codes**

Type number	Marking codes
WN3S40200CWT	WN3S40 200CWT

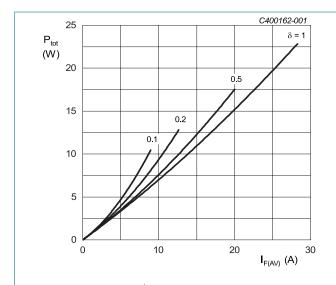
# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

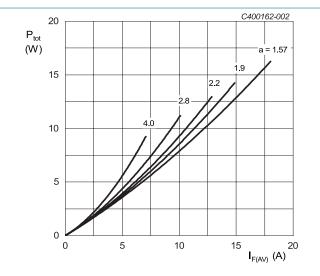
Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage			200	V
$V_{RWM}$	crest working reverse voltage			200	V
$V_R$	reverse voltage	DC		200	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3		20	А
$I_{O(AV)}$	average output current	$\delta$ = 0.5 ; square-wave pulse; both diodes conducting		40	А
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4		360	Α
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		396	А
T <sub>stg</sub>	storage temperature			-40 to 175	°C
T <sub>j</sub>	junction temperature		[1]	-40 to 175	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient:  $dP_{tot}/dT_j < 1/R_{th(j-a)}$ 



$$\begin{split} \textbf{I}_{\text{F(AV)}} &= \textbf{I}_{\text{F(RMS)}} \times \sqrt{\delta} \\ \textbf{V}_{\text{o}} &= 0.641 \text{ V; R}_{\text{s}} = 0.0059 \text{ }\Omega \\ \end{split}$$
 Fig. 1. Forward power dissipation as a function of average forward current; square waveform;

maximum values; per diode



a = form factor =  $I_{F(RMS)}$  /  $I_{F(AV)}$ V<sub>o</sub> = 0.641 V;  $R_s$  = 0.0059  $\Omega$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

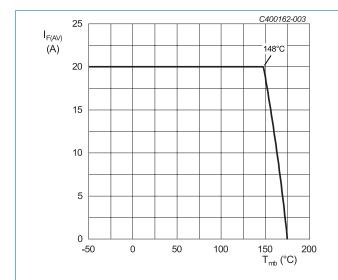


Fig. 3. Average forward current as a function of heatsink temperature; maximum values; per diode

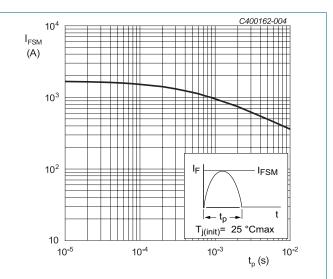


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values; per diode

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to	with heatsink compound; per diode; Fig. 5		-	-	1.54	K/W
	heatsink	with heatsink compound; both diodes conducting		-	-	0.78	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air		-	40	-	K/W

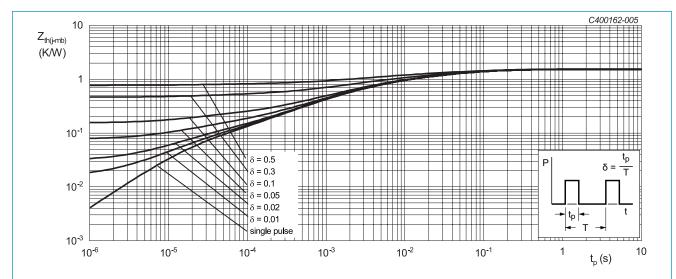
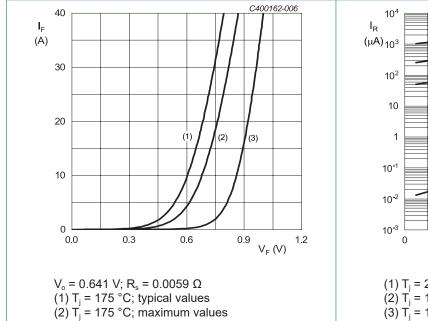


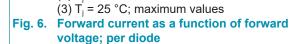
Fig. 5. Transient thermal impedance from junction to heatsink as a function of pulse duration; maximum values; per diode

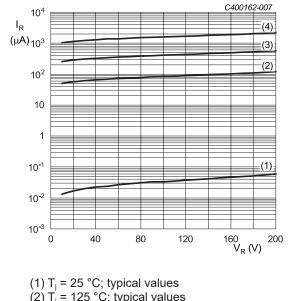
## 10. Characteristics

### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; per diode; <u>Fig. 6</u>		-	0.85	0.92	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 125 °C; per diode		-	0.74	-	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 175 °C; per diode; <u>Fig. 6</u>		-	0.69	0.76	V
I <sub>R</sub>	reverse current	$V_R = 200 \text{ V}; T_j = 25 \text{ °C}; \text{ per diode}; $ Fig. 7		-	0.1	5	μΑ
		$V_R = 200 \text{ V}; T_j = 125 \text{ °C}; \text{ per diode}; $ Fig. 7		-	0.2	-	mA

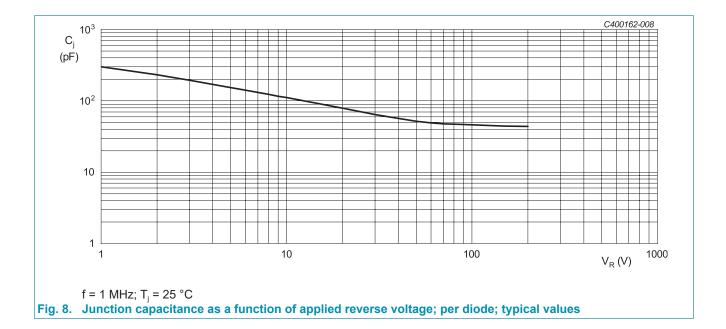




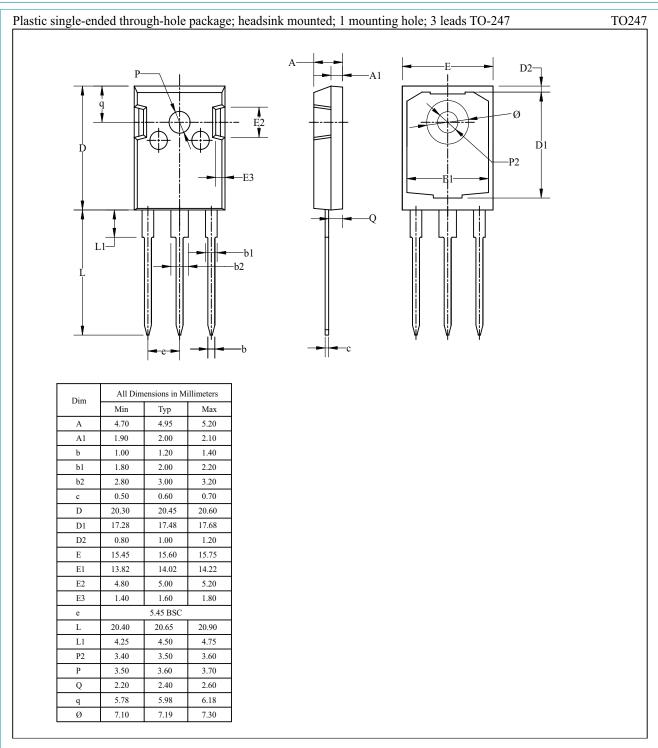


(1)  $T_j = 25$  °C; typical values (2)  $T_j = 125$  °C; typical values (3)  $T_j = 150$  °C; typical values (4)  $T_j = 175$  °C; typical values

Fig. 7. Reverse leakage current as a function of reverse voltage; per diode; typical values



# 11. Package outline



## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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